NSN 5961-00-254-3202

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-254-3202 **Inclosure Material:** Metal **Overall Length:** 0.297 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-base, emitter open and 90.0 collector to emitter reverse voltage and 7.0 breakdown voltage, emitter-to-base, collector open and 95.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 35.0 watts small-signal input power, common-collector preset **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**